

# STPS15L45CB

### LOW DROP POWER SCHOTTKY RECTIFIER

#### MAIN PRODUCTS CHARACTERISTICS

I <sub>F(AV)</sub>	2 x 7.5 A
V <sub>RRM</sub>	45 V
Tj (max)	150 °C
V <sub>F</sub> (max)	0.46 V

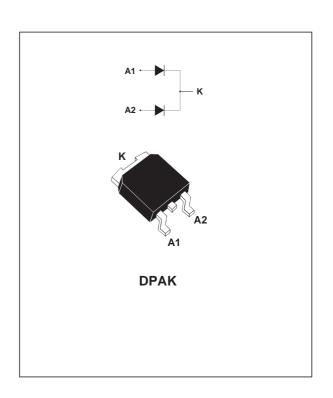
#### **FEATURES AND BENEFITS**

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW FORWARD VOLTAGE DROP
- AVALANCHE CAPABILITY SPECIFIED



Dual center tab Schottky rectifier suited for Switch Mode Power Supply and high frequency DC to DC converters.

Package in DPAK, this device is intended for use in low voltage, high frequency inverters, free-wheeling and polarity protection applications.



#### ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter	Value	Unit		
V <sub>RRM</sub>	Repetitive peak reverse voltage			45	V
I <sub>F(RMS)</sub>	RMS forward current			10	А
I <sub>F(AV)</sub>	Average forward current	Tc = 140°C	Per diode	7.5	
		$\delta = 0.5$	Per device	15	A
I <sub>FSM</sub>	Surge non repetitive forward current	tp = 10 ms sir	nusoidal	75	Α
I <sub>RRM</sub>	Peak repetitive reverse current	tp=2 µs squa	re F=1kHz	1	Α
P <sub>ARM</sub>	Repetitive peak avalanche power tp = 1µs Tj = 25°C			3700	W
T <sub>stg</sub>	Storage temperature range			- 65 to + 175	°C
Tj	Maximum operating junction temperature *			150	°C
dV/dt	Critical rate of rise reverse voltage			10000	V/µs

\* :  $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  thermal runaway condition for a diode on its own heatsink

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#### THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
R <sub>th(j-c)</sub>	Junction to case	Per diode Total	4 2.4	°C/W
R <sub>th(c)</sub>	Coupling	Total	0.7	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T j(\text{diode 1}) = P(\text{diode1}) \times R_{\text{th(j-c)}}(\text{Per diode}) + P(\text{diode 2}) \times R_{\text{th(c)}}$ 

STATIC ELECTRICAL CHARACTERISTICS (per diode)

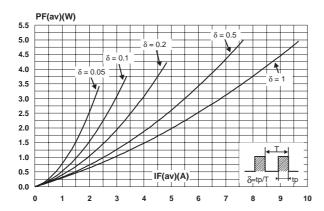
Symbol	Parameter	Tests Conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> *	Reverse leakage current	Tj = 25°C	$V_R = V_{RRM}$			1	mA
		Tj = 125°C			23	45	mA
V <sub>F</sub> *	Forward voltage drop	Tj = 25°C	I <sub>F</sub> = 7.5 A			0.52	V
		Tj = 125°C	I <sub>F</sub> = 7.5 A		0.40	0.46	
		Tj = 25°C	I <sub>F</sub> = 12 A			0.60	
		Tj = 125°C	I <sub>F</sub> = 12 A		0.49	0.57	
		Tj = 25°C	I <sub>F</sub> = 15 A			0.64	
		Tj = 125°C	I <sub>F</sub> = 15 A		0.53	0.63	

Pulse test: \* tp = 380  $\mu$ s,  $\delta$  < 2%

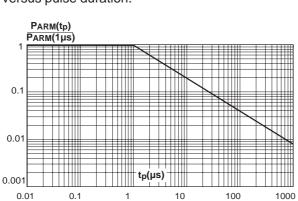
To evaluate the conduction losses use the following equation :

 $P = 0.29 \text{ x } I_{F(AV)} + 0.023 I_{F}^{2}_{(RMS)}$ 

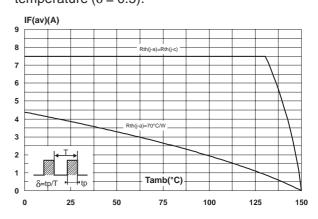
Fig. 1: Conduction losses versus average current.



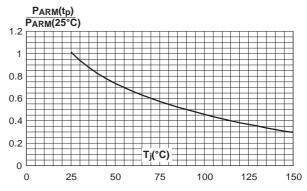
**Fig. 3:** Normalized avalanche power derating versus pulse duration.



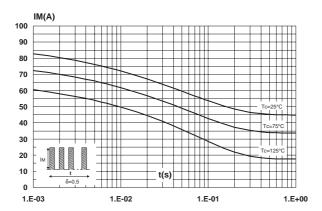
**Fig. 2:** Average forward current versus ambient temperature ( $\delta = 0.5$ ).



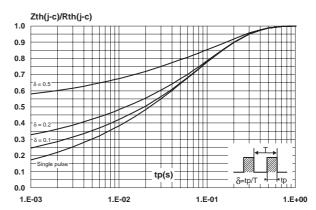
**Fig. 4:** Normalized avalanche power derating versus junction temperature.



**Fig. 5:** Non repetitive surge peak forward current versus overload duration (maximum values).



**Fig. 6:** Relative variation of thermal impedance junction to case versus pulse duration.



**Fig. 7:** Reverse leakage current versus reverse voltage applied (typical values).

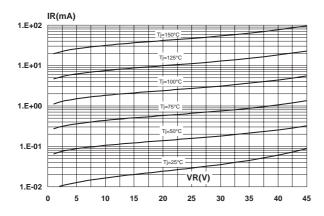


Fig. 8 Junction capacitance versus reverse voltage applied (typical values).

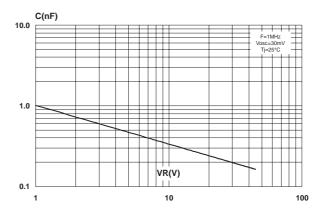
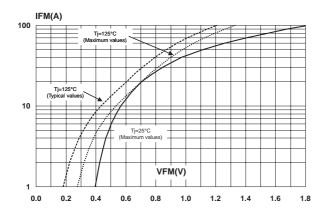
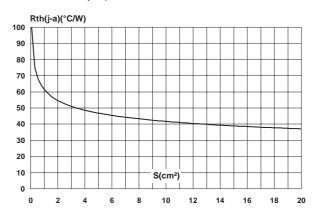


Fig. 9: Forward voltage drop versus forward current.

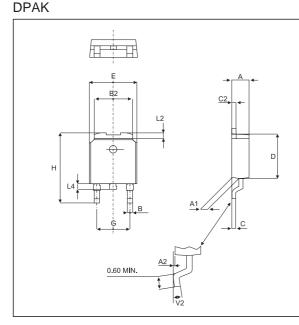


**Fig. 10:** Thermal resistance junction to ambient versus copper surface under tab (epoxy printed board FR4,  $Cu = 35\mu m$ ).



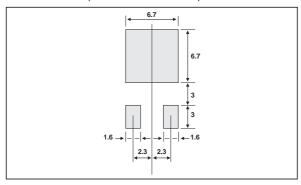
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## PACKAGE MECHANICAL DATA



	DIMENSIONS				
REF.	. Millimeters		Inches		
	Min.	Max	Min.	Max.	
А	2.20	2.40	0.086	0.094	
A1	0.90	1.10	0.035	0.043	
A2	0.03	0.23	0.001	0.009	
В	0.64	0.90	0.025	0.035	
B2	5.20	5.40	0.204	0.212	
С	0.45	0.60	0.017	0.023	
C2	0.48	0.60	0.018	0.023	
D	6.00	6.20	0.236	0.244	
E	6.40	6.60	0.251	0.259	
G	4.40	4.60	0.173	0.181	
Н	9.35	10.10	0.368	0.397	
L2	0.80 typ.		0.031 typ.		
L4	0.60	1.00	0.023	0.039	
V2	0°	8°	0°	8°	

#### FOOTPRINT (dimensions in mm)



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS15L45CB	S15L45C	DPAK	0.30 g	75	Tube
STPS15L45CB-TR	S15L45C	DPAK	0.30 g	2500	Tape & reel

#### ■ EPOXY MEETS UL94,V0

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